Keysight Technologies MXG X-Series Signal Generators N5181B Analog & N5182B Vector

9 kHz to 3 or 6 GHz

Data Sheet





Pure and precise

On the path to better performance, the Keysight Technologies, Inc. MXG X-Series signal generators are fine-tuned to be your "golden transmitter" in R&D. Whether you're pushing for a linear RF chain or an optimized link budget, the analog and vector MXG models deliver what you need: phase noise, ACPR, channel coding, and more. Take your devices and designs to the limit with the MXG.

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Definitions and Conditions

Specifications represent warranted performance of a calibrated instrument that has been stored for a minimum of 2 hours within the operating temperature range of 0 to 55 °C, unless otherwise stated, and after a 45 minute warm-up period. The specifications include measurement uncertainty. Data represented in this document are specifications unless otherwise noted.

Typical (typ) describes additional product performance information that is not covered by the product warranty. It is performance beyond specifications that 80 percent of the units exhibit with a 90 percent confidence level at room temperature (approximately 25 °C). Typical performance does not include measurement uncertainty.

Nominal (nom) values indicate the expected mean or average performance, or an attribute whose performance is by design, such as the 50 ohm connector. This data is not warranted and is measured at room temperature (approximately $25\ ^{\circ}\text{C}$).

Measured (meas) describes an attribute measured during the design phase for purposes of communicating expected performance, such as amplitude drift vs. time. This data is not warranted and is measured at room temperature (approximately 25 °C).

Frequency Specifications

Option 503	9 kHz (5 MHz IQ mode) to 3	GHz
Option 506	9 kHz (5 MHz IQ mode) to 6	GHz
0.001 Hz		
Adjustable in nominal	0.1 ° increments	
Band	Frequency range	N
1	9 kHz to < 5 MHz	1 (digital synthesis)
1	5 to < 250 MHz	1
2	250 to < 375 MHz	0.25
3	375 to < 750 MHz	0.5
4	750 to < 1500 MHz	1
5	1500 to < 3000.001 MHz	2
6	3000.001 to 6000 MHz	4
	Option 506 0.001 Hz Adjustable in nominal Band 1 1 2 3 4 5	Option 506 9 kHz (5 MHz IQ mode) to 6 0.001 Hz Adjustable in nominal 0.1 ° increments Band Frequency range 1 9 kHz to < 5 MHz 1 5 to < 250 MHz 2 250 to < 375 MHz 3 375 to < 750 MHz 4 750 to < 1500 MHz 5 1500 to < 3000.001 MHz

^{1.} N is a factor used to help define certain specifications within the document.

Frequency switching speed 1,2					
	Standard	Option UNZ ³	Option UNZ, typical		
CW mode					
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 µs		
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs		
Digital modulation on (N5182B only)				
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 1.05 ms		
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs		

^{1.} Time from receipt of SCPI command or trigger signal to within 0.1 ppm of final frequency or within 100 Hz, whichever is greater.

^{2.} With internal channel corrections on, the frequency switching speed is < 1.3 ms, measured for list mode and SCPI mode cached frequency points. For the initial frequency point in SCPI mode the time is < 3.3 ms, measured. The instrument will automatically cache the most recently used 1024 frequencies. There is no speed degradation for amplitude-only changes.

^{3.} Specifications apply when status register updates are off. For export control purposes CW switching speed to within 0.05% of final frequency is 190 µs (measured).

Frequency reference	
Accuracy	 ± (time since last adjustment x aging rate) ± temperature effects ± line voltage effects ± calibration accuracy
Internal time base reference oscillator aging rate ¹	< ± 1 x 10^-7/year < ± 5 x 10^-10/day after 30 days
Initial achievable calibration accuracy	± 4 x 10^-8 or ± 40 ppb
Adjustment resolution	< 1 x1 0^-10
Temperature effects	< ± 2 x 10^-8, nominal
Line voltage effects	< ± 1 x 10^-9 for ± 10% change, nominal
Reference output	
Frequency	10 MHz
Amplitude	≥ +4 dBm, nominal into 50 Ω load
External reference input	
Input frequency, standard	10 MHz
Input frequency, Option 1ER	1 to 50 MHz (in multiples of 0.1 Hz) ²
Stability	Follows the stability of external reference input signal
Lock range	± 1 ppm
Amplitude	–3 dBm to +20 dBm, nominal
Impedance	50 Ω, nominal
Waveform	Sine or square
Sweep modes (frequency and amplitude)	
Operating modes	Step sweep (equally spaced frequency and amplitude or logarithmically spaced frequency steps) List sweep (arbitrary list of frequency and amplitude steps) Simultaneously sweep waveforms with N5182B; see Baseband Generator section for more detail
Sweep range	Within instrument frequency range
Dwell time	100 µs to 100 s
Number of points	2 to 65535 (step sweep) 1 to 3201 (list sweep)
Step change	Linear or logarithmic
Triggering	Free run, trigger key, external, timer, bus (GPIB, LAN, USB)

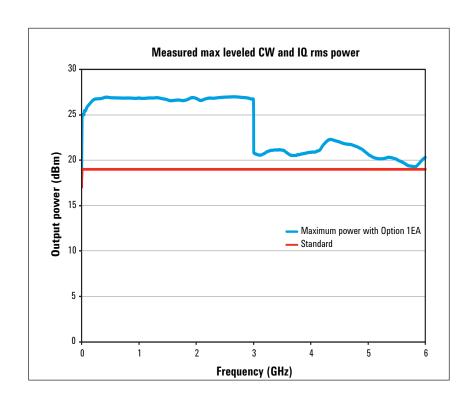
^{1.} Not verified by Keysight N7800A TME Calibration and Adjustments Software. Daily aging rate may be verified as a supplementary chargeable service, on request.

^{2.} Close-in phase noise will degrade when reference input is tuned away from 10 MHz.

Amplitude Specifications

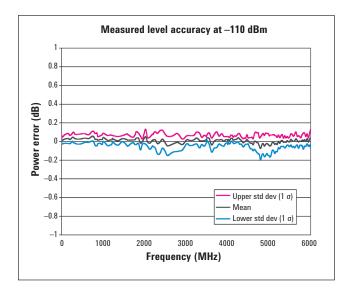
Output parameters	·			
Settable range	+30 to -144 dBm			
Resolution	0.01 dB			
Step attenuator	0 to 130 dB in 5 dB s	teps electronic type		
Connector	Type N 50 Ω, nomina	Type N 50 Ω, nominal		
Max output power ¹ () = typica	al			
Frequency	Standard	Option 1EA		
9 kHz to 10 MHz	+13 dBm	+17 dBm (+18 dBm)		
> 10 MHz to 3 GHz	+18 dBm	+24 dBm (+26 dBm)		
> 3 to 5 GHz	+16 dBm	+19 dBm (+20 dBm)		
> 5 to 6.0 GHz	+16 dBm	+18 dBm (+19 dBm)		

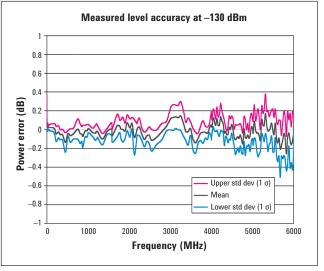
^{1.} Quoted specifications between 20 °C and 30 °C. Maximum output power typically decreases by 0.01 dB/°C for temperatures outside this range.

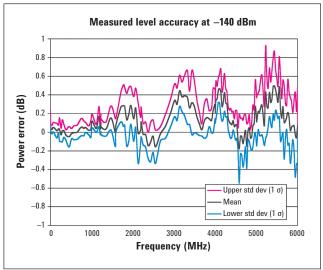


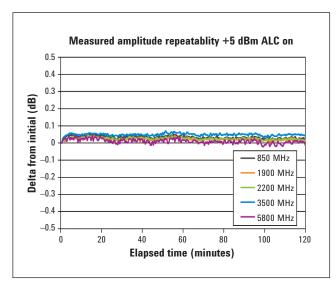
Absolute level accuracy in CW mode	1 (ALC on) ()= typical			
	Standard		Option 1EQ	
Range	Max power to -60 dBm	< -60 to -110 dBm	< -110 to -127 dBm	
9 to 100 kHz	(± 0.6 dB)	(± 0.9 dB)		
100 kHz to 5 MHz	± 0.8 dB (± 0.3)	± 0.9 dB (± 0.3)		
> 5 MHz to 3 GHz	± 0.6 dB (± 0.3)	± 0.8 dB (± 0.3)	± 1.5 dB (± 0.5)	
> 3 to 6 GHz	± 0.6 dB (± 0.3) ± 1.1 dB (± 0.3)		± 1.6 dB (± 0.6)	
Absolute level accuracy in CW mode	e (ALC off, power search run, rel	ative to ALC on)		
9 kHz to 6 GHz	± 0.15 dB, typical			
Absolute level accuracy in digital I/0	Q mode (N5182B only)			
(ALC on, relative to CW, W-CDMA 1	DPCH configuration < +10 dBm)			
5 MHz to 6 GHz	± 0.25 dB, (0.05 dB)			

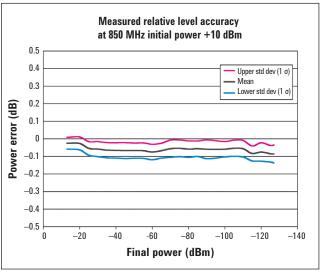
^{1.} Quoted specifications between 20 °C and 30 °C. For temperatures outside this range, absolute level accuracy degrades by 0.01 dB/°C. Output power may drift up to 0.10 dB < 3 GHz and 0.15 dB > 3 GHz per g/kg change in absolute humidity (nom).





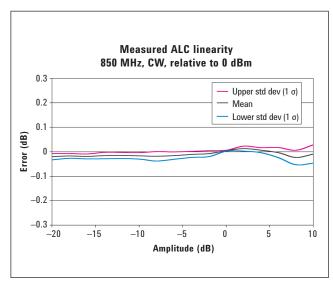


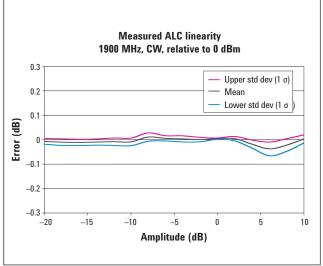




Repeatability measures the ability of the instrument to return to a given power setting after a random excursion to any other frequency and power setting. It should not be confused with absolute level accuracy.

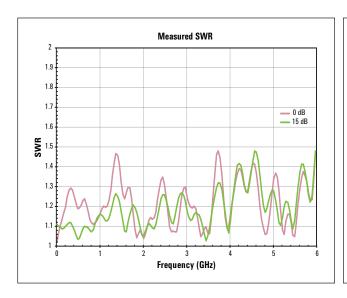
Relative level accuracy measures the accuracy of a step change from any power level to any other power level. This is useful for large changes (such as 5 dB steps).

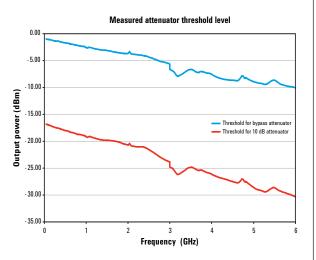




SWR (measured CW mode))1		
Frequency	Attenuator state		
	Bypass	0 to 10 dB	15 dB or more
≤ 1.0 GHz	< 1.3:1	< 1.35:1	< 1.2:1
> 1.0 to 2 GHz	< 1.55:1	< 1:5:1	< 1.3:1
> 2 to 3 GHz	< 1.8:1	< 1.5:1	< 1.45:1
> 3 to 4 GHz	< 1.5:1	< 1.6:1	< 1.7:1
> 4 to 6 GHz	< 1.9:1	< 1.6:1	< 1.6:1

^{1.} SWR < 1.60:1 below 30 kHz.





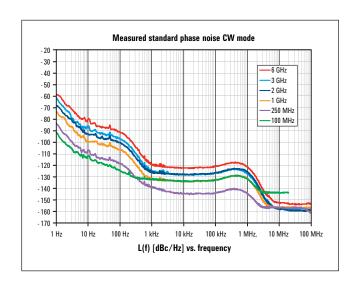
Maximum reverse power, nominal			
< 1 GHz	50 W		
> 1 to 2 GHz	25 W		
> 2 to 6 GHz	20 W		
Max DC voltage	50 VDC		
Trip level	2 W		
Amplitude switching speed ¹	Standard	Option UNZ	Option UNZ, typical
CW mode			
SCPI mode	≤ 5 ms, typical	≤ 750 µs	≤ 650 µs
Power search SCPI mode	< 12 ms, measured		
List/step sweep mode	≤ 5 ms, typical	≤ 500 µs	≤ 300 µs
Digital modulation on (N5182B only)			
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 µs
Power search SCPI mode	< 12 ms, measured		
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 400 µs
Alternate power level control (N5182	2B only)		
Switching time (via waveform markers)	20 μs within ± 1 dB, measu	ıred	
Functional power range	-15 dBm to -144 dBm, me	asured	
User flatness correction			
Number of points	3201		
Number of tables	Dependent on available free	e memory in instrument; 10,	000 maximum
Entry modes	USB/LAN direct power me USB/GPIB power meter co		d USB to GPIB, remote bus and manual
Sweep modes			
	See Frequency Specificatio	ns section for more detail	

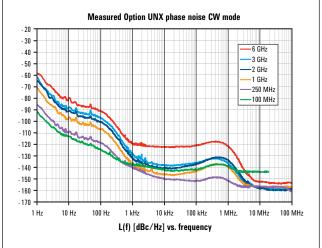
^{1.} Time from receipt of SCPI command or trigger signal to amplitude settled within 0.2 dB. Switching speed specifications apply when status register updates are off.

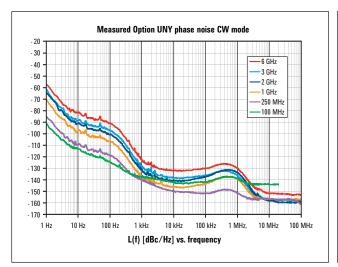
Spectral Purity Specifications

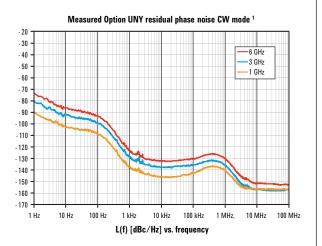
		oise (dBc/Hz, CW, at 2		ЛСА					
5 MHz to < 250	J IVINZ		-129 (-133)						
250 MHz			-140 (-143)						
500 MHz			-135 (-139)						
1 GHz			-131 (-134)						
2 GHz			-124 (-127)						
3 GHz			-123 (-127)						
4 GHz			-118 (-122)						
6 GHz			-116 (-121)						
•	•	e noise (dBc/Hz, CW, at		typical 1					
5 MHz to < 250) MHz		-140 (-143)						
250 MHz			-144 (- 150)						
500 MHz			-143 (-150)						
1 GHz			-141 (-146)						
2 GHz			-135 (-141)	–135 (–141)					
3 GHz			-131 (-137)						
4 GHz			-118 (-122)						
6 GHz			-117 (-121)						
Option UNY abs	solute SSB phase	noise (CW) () = meas	ured ¹						
Frequency	1 Hz	10 Hz	100 Hz	1 kHz	10 kHz	100 kHz			
100 MHz	(-91)	(–113)	(-124)	(–137)	(-142)	(-142)			
249 MHz	(-85)	-93 (-110)	-103 (-118)	-130 (-137)	-139 (-142)	-138 (-142)			
250 MHz	(–85)	-96 (-110)	-104 (-118)	-127 (-139)	-144 (-150)	-147 (-152)			
500 MHz	(-74)	-89 (-100)	-98 (-109)	-125 (-139)	-139 (-149)	-145 (-149)			
1 GHz	(-70)	-87 (-97)	-93 (-106)	-123 (-136)	-141 (-146)	-140 (-143)			
2 GHz	(-65)	-79 (-90)	-85 (-101)	-114 (-131)	-135 (-140)	-134 (-137)			
3 GHz	(-61)	-74 (-88)	-81 (-98)	-112 (-128)	-132 (-138)	-131 (-135)			
4 GHz	(-61)	-73 (-84)	-79 (-95)	-110 (-124)	-130 (-134)	-127 (-131)			
6 GHz	(–57)	-69 (-81)	-76 (- 91)	-107 (-121)	-126 (-132)	-125 (-129)			

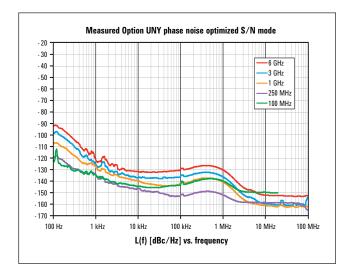
^{1.} From 20 to 30 °C, excludes mechanic vibration, measured @ +10 dBm or maximum specified power, whichever is less.

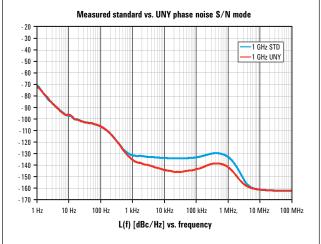


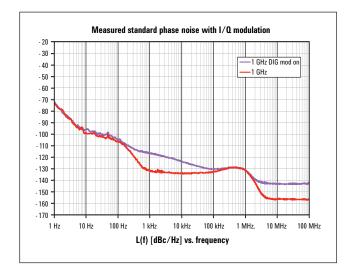


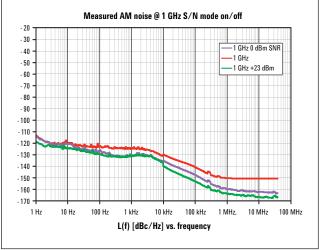












5 MHz to 6 GHz	< N x 2 Hz (measured) (s	see N value in frequer	ncy band table)		
Residual AM (CW mode, 0.3 to 3 kHz B	W, rms, +5 dBm)				
100 kHz to 3 GHz	< 0.01% (measured)				
Harmonics (CW mode)					
Range	Standard < +4 dBm		Option 1EA < +12 dB	m	
9 kHz to 3 GHz	<-35 dBc		<-30 dBc		
> 3 to 4 GHz	< –35 dBc, typical		< –35 dBc, typical		
> 4 to 6 GHz	< –53 dBc, typical		< -40 dBc, typical		
Nonharmonics (CW mode) () = typica	al				
Range	> 10 KHz offset				
	Standard (dBc)		UNX or UNY (dBc)		
9 kHz to < 5 MHz	–65, nominal		–65, nominal		
5 to < 250MHz	–75		-75 (- 80)		
250 to < 750 MHz	-87		-96 (-100)		
750 MHz to < 1.5 GHz	-87		-92 (-96)		
1.5 to < 3.0 GHz	-81		-86 (-90)		
3 to 6 GHz	–75		-80 (-84)		
Subharmonics (CW mode) () = typical					
9 kHz to 1.5 GHz	None				
> 1.5 to 3 GHz	-77 dBc (-91)				
> 3 to 6 GHz	-74 dBc (-81)				
Jitter (standard phase noise) ²					
Carrier frequency	SONET/SDH data rate	rms jitter BW	μUI rms, typical	Seconds, typical	
155 MHz	155 MB/s	100 Hz to 1.5 MHz	91.8	0.6 ps	
622 MHz	622 MB/s	1 KHz to 5 MHz	50.5	81 fs	
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	198	80 fs	
Jitter (UNX or UNY phase noise) ²					
Carrier frequency	SONET/SDH data rate	rms jitter BW	μUI rms, measured	Seconds, measured	
155 MHz	155 MB/s	100 Hz to 1.5 MHz	40	0.25 ps	
622 MHz	622 MB/s	1 KHz to 5 MHz	21	33 fs	
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	72	29 fs	
Phase coherence (Option 012)					
LO input frequency range	250 MHz to 6 GHz, nomi	nal			
LO input power range	0 to +12 dBm, nominal				
LO output frequency range	250 MHz to 6 GHz, nomi	nal			
LO output power range	0 to +12 dBm, nominal				

^{1. &}lt; 3 GHz fixed 100 MHz spur is specified @ -78 dBc. In signal-to-noise optimization mode 100 MHz spur is < -100 dBc, measured.

^{2.} Calculated from phase noise performance in CW mode at +10 dBm. For other frequencies, data rates, or bandwidths, please consult your sales representative.

Analog Modulation Specifications

Frequency bands					
Band #	Frequency range	N			
1	9 kHz to < 5 MHz	(digital synthesis)			
1	5 to < 250 MHz	1			
2	250 to < 375 MHz	0.25			
3	375 to < 750 MHz	0.5			
4	750 to < 1500 MHz	1			
5	1500 to < 3000.001 MHz	2			
6	3000.001 to 6000 MHz	4			
Frequency modulation (Option UNT) (S	ee N value above)				
Max deviation	N × 4 MHz, nominal ³				
Resolution	0.025% of deviation or 1 Hz, whichev	ver is greater, nominal			
Deviation accuracy	< ± 2% + 20 Hz (1 kHz rate, deviation	n is N x 50 kHz)			
Modulation frequency response	1 dB bandwidth	DC/5 Hz to 3 MHz, nominal			
@ 100 KHz rate	3 dB bandwidth	DC/1 Hz to 7 MHz, nominal			
Carrier frequency accuracy	,	$< \pm 0.2\%$ of set deviation + $(N \times 1 \text{ Hz})^{1}$			
Relative to CW	$< \pm 0.06\%$ of set deviation + (N × 1 F	lz), typical ²			
Distortion	< 0.4% [1 kHz rate, deviation is N x 5	0 kHz]			
FM using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nominal			
	Input impedance	50 $\Omega/600~\Omega/1~M~\Omega$, nominal			
	Paths	FM path 1 and FM path 2 are summed internally for composite modulation			
Phase modulation (Option UNT) (See N	value above)				
Maximum deviation	Normal bandwidth	N × 2 radians, nominal			
	High-bandwidth mode	N × 0.2 radians, nominal			
Frequency response	Normal bandwidth (3 dB)	DC to 1 MHz, nominal			
	High-bandwidth mode (3 dB)	DC to 4 MHz, nominal			
Resolution	0.1% of deviation				
Deviation accuracy	< + 0.5% + 0.01 rad, typical [1 kHz ra	te, normal bandwidth mode]			
Distortion	< 0.2%, typical [1 kHz rate, deviation	normal bandwidth mode]			
ΦM using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nominal			
	Input impedance	50 Ω or 600 Ω or 1 M Ω , nominal			
	Paths	ΦM path 1 and ΦM path 2 are summed internally for composite modulation			
		· · · · · · · · · · · · · · · · · · ·			

^{1.} Specification valid for temperature changes of less than \pm 5 °C since last DCFM calibration.

^{2.} Typical performance immediately after a DCFM calibration.

^{3.} Digital synthesis band FM deviation is 5 MHz.

AM depth type	Linear or expo	nential					
Maximum depth	100%						
Depth resolution		0.1% of depth (nom)					
AM depth error	f < 5 MHz	()	< 1.5% of s	etting + 1% (typ 0.5% of setting + 1%)			
@1 KHz rate and < 80% depth	5 MHz < f < 2	GHz	< 3% of set				
	2 < f < 3 GHz				al 3% of setting + 19	%)	
Total harmonic distortion			30% depth	< 0.25%, ty		-1	
@ 1 KHz rate	F < 5 MHz		80% depth	< 0.5%, typ			
	5 MHz < f < 2	GHz	30% depth	< 2%			
	(2 to 3 GHz is	typical)	80% depth	< 2%			
Frequency response	30% depth, 3	dB BW	DC/10 Hz to	o 50 KHz			
Frequency response wideband AM (N5182B only)	Rates ALC off	/on:	DC/800 Hz	to 80 MHz, nom	inal		
AM inputs using external inputs 1 or 2	Sensitivity		+1 V peak f 2.2 V peak)	+1 V peak for indicated depth (Over-range can be 200% or 2.2 V peak)			
	Input impedar	ice	50 Ω or 600	50 Ω or 600 Ω or 1M Ω , Damage level: ± 5 V max			
	Paths AM path 1 and AM path 2 are summed internally for composi modulation					ly for composite	
Wideband AM inputs	Sensitivity 0.5 V = 100% (0.5 V DC offset required)						
(N5182B only)	Input impedar	ice	50 Ω, nomir	50 Ω , nominal (I input)			
Simultaneous and composite mod	ulation ²						
Simultaneous modulation	except: FM an simultaneousl	d phase mod y generated I, and FM ca	dulation cannot be using the same mo	combined and two) may be simultaned wo modulation types for example, the baulate the output RF	s cannot be aseband I/Q	
Composite modulation				•	h are summed inter f internal or externa		
	AM	FM	Phase	Pulse	Internal IQ 1	External IQ ¹	
AM	+	+	+	+	+	+	
FM	+	+	_	+	+	+	
Phase	+	_	+	+	+	+	
Pulse	+	+	+	-	+	+	
Internal I/Q(1)	+	+	+	+	_	+	
External IQ (1)	+	+	+	+	+	_	

^{1.} AM specifications apply 6 dB below maximum specified power from 20 to 30 °C.

^{2.} IQ modulation available on N5182B.

External modulation inputs (Ontion LINT required for FM_AM_and phase mod	Iulation inputs; Option UNW required for pulse modulation inputs)
EXT1	AM, FM, PM
EXT2	AM, FM, PM
PULSE	Pulse (50 Ω only)
I	Wideband AM (50 Ω only, N5182B only)
Input impedance	50Ω , 1 MΩ, 600Ω , DC and AC coupled
Standard internal analog modulation source	oo x, 1 mx, ooo x, 50 and A0 coupled
(Single sine wave generator for use with AM, FM	phase modulation requires Option UNIT or 303)
Waveform	Sine, square, triangle, positive ramp, negative ramp
Rate range	0.1 Hz to 2 MHz (tunable to 3 MHz)
Resolution	0.1 Hz
Frequency accuracy	Same as RF reference source, nominal
LF audio output	0 to 5 V peak into 50 Ω, –5V to 5 V offset, nominal
Multifunction generator (Option 303)	o to 3 v peak into 30 12, —3 v to 3 v onset, nominal
The multifunction generator option (Option 303) of to five simultaneously using the composite module	consists of seven waveform generators that can be set independently with up lation features in AM, FM/PM, and LF out
Waveform	
Function generator 1	Sine, triangle, square, positive ramp, negative ramp, pulse
Function generator 2	Sine, triangle, square, positive ramp, negative ramp, pulse
Dual function generator	Sine, triangle, square, positive ramp, negative ramp, phase offset, and amplitude ratio for Tone 2 relative to Tone 1
Swept function generator	Sine, triangle, square, positive ramp, negative ramp Trigger: free run, trigger key, bus, external, internal, timer trigger
Noise generator 1	Uniform, Gaussian
Noise generator 2	Uniform, Gaussian
DC	Only for LF output –5 V to +5 V, nominal
Frequency parameters	
Sine wave	0.1 Hz to 10 MHz
Triangle, square, ramp, pulse	0.1 Hz to 1 MHz, nominal
Noise bandwidth	10 MHz, nominal
Resolution	0.1 Hz
Frequency accuracy	Same as RF reference source, nominal
Narrow pulse modulation (Option UNW) () = typical	
On/off ratio	(> 80 dB)
Rise/fall times (Tr, Tf)	< 10 ns; (7 ns)
Minimum pulse width ALC on/off	> 2 us/> 20 ns
Repetition frequency ALC on/off	10 Hz to 500 kHz/DC to 10 MHz
Level accuracy (relative to CW) ALC on/off ²	< ± 1.0 (± 0.5) dB/(< ± 0.5) dB
Width compression (RF width relative to video out)	(<5 ns)
1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	· · ·

^{1.} Pulse specifications apply to frequencies > 500 MHz. Operable down to 10 MHz.

^{2.} With power search on.

Video feed-through $^1 \le 3GHz/> 3GHz$	(< 50 mV/< 5mV)
Video delay (ext input to video)	30 ns, nominal
RF delay (video to RF output)	20 ns, nominal
Pulse overshoot	(< 15%)
Input level	+1 Vpeak = RF on into 50 Ω, nominal
T1 11 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	

Td video delay (variable)

Tw video pulse width (variable)

Tp pulse period (variable)

Tm RF delay

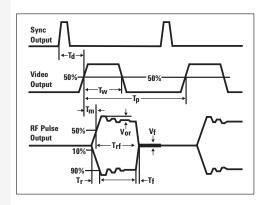
Trf RF pulse width

Tf RF pulse fall time

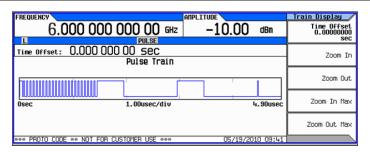
Tr RF pulse rise time

Vor pulse overshoot

Vf Video feedthrough



Internal pulse generator (included with Option	n UNW)				
Modes	Free-run, square, triç external pulse	Free-run, square, triggered, adjustable doublet, trigger doublet, gated, and external pulse			
Square wave rate	0.1 Hz to 10 MHz, 0.	1 Hz resolution, nominal			
Pulse period	30 ns to 42 seconds	, nominal			
Pulse width	20 ns to pulse period	d –10 ns, nominal			
Resolution	10 ns				
Adjustable trigger delay	(– pulse period + 10	ns) to (pulse width -10 ns)			
Settable delay	Free run	–3.99 to 3.97 μs			
	Triggered	0 to 40 s			
Resolution (delay, width, period)	10 ns, nominal				
Pulse doublets	1st pulse delay	(Relative to sync out) 0 to 42 s - pulse width - 10 ns			
	1st pulse width	500 ns to 42 s – delay – 10 ns			
	2nd pulse delay	0 to 42 s – (Delay 1 + Width 2) – 10 ns			
	2nd pulse width	20 ns to 42 s - (Delay 1 + Delay 2) - 10 ns			
Pulse train generator Option 320 (requires Op	tion UNW)				
Number of pulse patterns	2047				
On/off time range	20 ns to 42 sec				



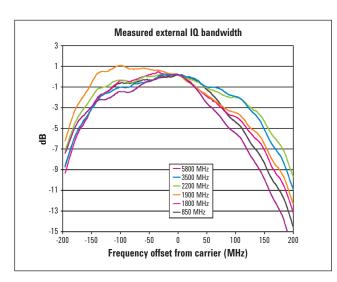
^{1.} Video feed through applies to power levels < +10 dBm.

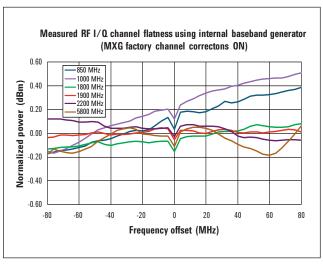
Vector Modulation Specifications

N5182B only

I/Q modulator external inputs ¹				
Bandwidth	Baseband (I or Q) Up to 100 MHz baseband, nominal RF (I+Q) Up to 200 MHz RF, nominal			
I or Q offset	± 100 mV (200 uV resolution	1)		
I/Q gain balance	± 4 dB (0.001 dB resolution)			
IQ attenuation	0 to 50 dB (0.01 dB resolution	on)		
Quadrature angle adjustment	± 200 units (0.1 units resolu	tion)		
Full scale input drive (I+Q)	0.5 V into 50 Ω, nominal			
Internal I/Q baseband generator adjustme	nts ^{1, 2} (Options 656 and 657)			
I/Q offset	± 20% (0.025% resolution)			
I/Q gain	± 1 dB (0.001 dB resolution)			
Quadrature angle adjustment	± 10 ° (0.01 degrees resolut	ion)		
I/Q phase	± 360.00 ° (0.01 degrees res	± 360.00 ° (0.01 degrees resolution)		
I/Q skew	± 800.00 ns (1 picosecond resolution)			
I/Q delay	± 250.00 ns (1 picosecond resolution)			
External I/Q outputs ¹				
Impedance	50 Ω, nominal per output			
	100 Ω, nominal differential of	putput		
Туре	Single-ended or differential	(Option 1 EL)		
Maximum voltage per output	1 V peak-to-peak or 0.5 V pe	eak		
Bandwidth (I, Q)	Baseband (I or Q)	80 MHz, nominal (Option 656 and 657)		
	RF (I+Q) 160 MHz, nominal (Option 656 and 657)			
Amplitude flatness	± 0.2 dB measured with cha	nnel corrections optimized for IQ output		
Phase flatness	± 2.5 degrees measured wit	± 2.5 degrees measured with channel corrections optimized for IQ output		
Common mode I/Q offset	± 1.5 V into 50 Ω (200 uV resolution)			
Differential mode I or Q offset	\pm 50 mV into 50 Ω (200 uV resolution)			

- 1. I/Q adjustments represent user intverface nominal parameter ranges and not specifications.
- 2. Internal IQ adjustments apply to RF out and IQ outputs simultaneously.





Internal real-time complex digital I/Q filters (included with Option 656) Factory channel correction (256 taps) Corrects the linear phase and amplitude response of the baseband IQ and RF outputs of the signal generator using factory calibration arrays. (default mode is off) RF amplitude flatness (160 MHz) ± 0.2 dB measured RF phase flatness (160 MHz) ± 2 degrees measured User channel correction (256 taps) Automated routine uses power sensor to correct for linear phase and amplitude response of DUT (equalizer). See Users Guide for more details. Recommended max amplitude error for ± 15 dB correction Recommended max phase error for ± 25 degrees correction Equalization filter (256 taps) User can download and apply inverse or custom phase and amplitude response coefficients from tools such as MATLAB, 89600 VSA or SystemVue to correct for linear errors of DUT/system. See Users Guide for more details. Baseband generator (Options 656 and 657) Channels 2 [I and Q]

Resolution	16 bits [1/65,536]			
Sample rate	Option 656	100 Sa/s to 100 MSa/s		
	Option 656 and 657	100 Sa/s to 200 MSa/s		
RF (I+Q) bandwidth	Option 656	80 MHz, nominal		
	Option 656 and 657	160 MHz, nominal		
Interpolated DAC rate	800 MHz (waveforms only need OSR = 1.25)			
Frequency offset range	± 80 MHz			
Digital sweep modes	In list sweep mode each point in the list can along with user definable frequencies and a Specifications sections for more detail.	. ,		
Waveform switching speed ¹	SCPI mode	\leq 5 ms, measured (standard)		
	SCFI IIIode	≤ 1.2 ms, measured (Option UNZ)		
	List/step sweep mode	≤ 5 ms, measured (standard)		
	List/ Step Sweep mode	≤ 900 us, measured (Option UNZ)		
Waveform transfer rates	FTP LAN to internal SSD	10.7 MB/sec or 2.67 Msa/sec		
(measured, no markers, unencrypted)	Internal SSD to FTP LAN	7.7 MB/sec 1.92 Msa/sec		
	FTP LAN to BBG	8.2 MB/sec or 2.05 Msa/sec		
	FTP LAN to BBG encrypted	4 MB/sec or 1 Msa/sec		
	USB to BBG	19 MB/sec or 4.75 Msa/sec		
	BBG to USB	1.2 MB/sec or 300 Ksa/sec		
	Internal SSD to BBG	48 MB/sec or 12 Msa/sec		
	BBG to internal SSD	1.2 MB/sec or 300 Ksa/sec		
	SD card to BBG (Option 006)	2.7 MB/sec or 678 Ksa/sec		
	BBG to SD card (Option 006)	845 KB/sec or 211 Ksa/sec		

^{1.} SCPI mode switching speed applies when waveforms are pre-loaded in list sweep and sample rate \geq 10 MSa/s.

Arbitrary waveform memory	Maximum playback	32 Msa (standard)			
	capacity	512 Msa (Option 022)			
	oupuoity	1024 Msa (Option 0	23)		
	Maximum storage	3 GBytes/800 Msa	(standard)		
	capacity including	30 GBytes/7.5 Gsa	(Option 009)		
	markers	8 GBytes / 2 Gsa (O	ption 006)		
Waveform segments		60 samples to 32 M	sa (standard)		
	Segment length	60 samples to 512 Msa (Option 022)			
		60 samples to 1024	Msa (Option 023)		
	Minimum memory allocation per segment	256 samples			
	Maximum number of segments	8192			
Waveform sequences	Maximum number of sequences	> 2000 depending o	n non-volatile memory usage		
	Maximum number of	32,000 (standard)			
	segments/sequence	4 million (Option 022 or 023)			
	Maximum number of repetitions	65,535			
Triggers	Types		Continuous, single, gated, segment advance		
	Source		Trigger key, external, bus (GPIB, LAN, USB)		
		Continuous	Free run, trigger and run, reset and run		
	Modes	Single	No retrigger, buffered trigger, restart on trigger		
	ivioues	Gated	Negative polarity or positive polarity		
		Segment advance	Single or continuous		
	External coarse delay	time	5 ns to 40 s		
	External coarse delay	resolution	5 ns		
	Trigger latency (Single	trigger only)	356 ns + 1 sample clock period, nominal		
	Trigger accuracy (Sing	le trigger only)	± 2.5 ns, nominal		
			iate a FIFO clear. Therefore, the latency includes Sx sample period) ±1 sample clock period, nominal		
Multi-baseband generator	Fan out		1 master and up to 15 slaves		
synchronization mode	Trigger repeatability		< 1 ns, nominal		
(multiple sources)	Trigger accuracy		Same as normal mode		
	Trigger latency		Same as normal mode		
	Fine trigger delay rang	е	See Internal IQ Baseband section		
	Fine trigger delay reso	lution	See Internal IQ Baseband section		
	IQ phase adjustment r	ange	See Internal IQ Baseband section		

Markers	Markers are defined in a segment during the waveform generation process, or from the front panel; a marker can also be routed to the RF blanking, ALC hold functions, and alternate amplitude; see Users Guide for more information			
	Marker polarity	Negative, positive		
	Number of markers	4		
	RF blanking/burst on/off ratio	> 80 dB		
	Alternate amplitude control switching See amplitude section speed			
Real-time modulation FIR filter:	Filter Types: Nyquist, root-Nyquist, WCDMA, EDGE, Gaussian, rectangular, APCO 25 C4FM, IS-95, User FIR (Applies real-time FIR filtering when playing waveforms with OSR=1. Helps reduce waveform size for long simulation times. Option 660 not required.)			
Real-time baseband generator (Option 6	660)			
Real-time baseband generator required for real-time Signal Studio	Cellular real-time applications	LTE-FDD, LTE-TDD, HSPA+/W-CDMA, GSM/EDGE, cdma2000®		
applications 1	Real-time navigation	GPS, GLONASS, Galileo		
	Real-time video applications	DVB-T/T2/H/S/S2/C/J.83 Annex A/C, ISDB-T/		
	Note: Option 660 is not required for real-time custom modulation (Option 431)			
	Memory: Shares memory with Options 656 and 657			
	Triggering: Same as Options 656 and 657			
	Markers: 3 markers available, all other features are same as Options 656 and 657			
D: :: 11	000 (00 ()			

Digital baseband inputs/outputs (Option 003/004)

Options 003 and 004 activate the rear panel digital I/Q bus and enable connectivity to the N5102A digital signal interface module. In output mode (003), you can deliver realistic complex-modulated signals such as LTE, GPS, WLAN, custom pulses and many others directly to your digital devices and subsystems. In the input mode (004), the interface module ports your digital input to the signal generator's baseband system, providing a quick and easy way of upconverting to calibrated analog I/Q, IF, or RF frequencies. In both operating modes, the interface module adapts to your device with the logic type, data format, clock features, and signaling you require.

Data (requires N5102A)	
Digital data format	User-selectable: 2's complement or binary offset, IQ (I, I-bar, Q, Q-bar) or digital IF output (real, imaginary)
Data port	Dual 16-bit data buses support parallel, parallel IQ interleaved, parallel QI interleaved, or serial port configuration
N5102A connectors (breakout boards)	144-pin Tyco Z-Dok+ connects to break-out boards (included with N5102A) that interface with the following connector types: 68-pin SCSI, 38-pin dual AMP Mictor, 100-pin dual Samtec, 20-pin dual 0.1 inch headers, 40-pin dual 0.1 inch headers
Logic types	Single-ended: LVTTL, 1.5V CMOS, 1.8V CMOS, 2.5V CMOS, 3.3.V CMOS
	Differential: LVDS
Data output resampling	MXG baseband output is resampled to the arbitrary clock rate set by the user via real-time curve-fit calculations.

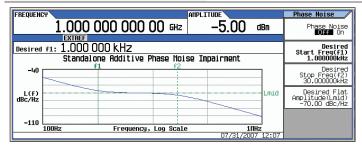
^{1.} See www.keysight.com/find/signalstudio for more information.

Clock (requires N5102A)				
Clock input	User selectable: internal clock, o breakout board)	device under test clock, or external clock (via SMA or		
	N5102A SMA Ext Clock In conn	ector: 50 Ω, 0 dBm nominal, 1 to 400 MHz		
Clock output	User selectable: via breakout bo	ard or SMA Clock Out connector		
	N5102A SMA Clock Out connector: 2 Vpp into load > 5K Ω from 1 to 100 kHz, 400 mVpp into 50 Ω load from 100 kHz to 400 MHz			
Sample rate (limited by MXG sample rate)	User-selectable in parallel mode up to a maximum 200 MHz, but limited by other user settings (see N5102A users guide for more details).			
	User-selectable in serial mode, t	the maximum rate is 400 MHz/word size.		
Bit rate (limited by MXG sample rate)	Parallel Up to 200 MHz x word s 2 parallel buses available	ize (1.6 Gbps LVDS, CMOS and LVTTL) per parallel bus,		
	Serial Up to 400 MHz per serial (CMOS/LVTTL) 32 lines available	line (400 Mbps LVDS) or 150 MHz per serial line (150 Mbps e		
Clocks per sample	In parallel output mode, the data	a sample can be held for 1, 2 or 4 clock cycles		
Clock to data skew	Coarse adjustment in 90° steps fr	om 0 to 270°; fine-adjustment in increments of 100 ps up to 5 ns		
Clock polarity	Clock signals may be inverted			
Frequency reference input	1 to 100 MHz BNC, 50 Ω, 3 dBm	± 6 dB		
Power supply (included on N5102A)	Output: 5V, 4A DC			
AWGN (Option 403)				
Туре	Real-time, continuously calculat	ed, and played using DSP		
Modes of operation	Standalone or digitally added to sig	gnal played by arbitrary waveform or real-time baseband generator		
Bandwidth	With Option 656	1 Hz to 80 MHz		
	With Option 656 and 657	1 Hz to 160 MHz		
Crest factor	15 dB			
Randomness	90 bit pseudo-random generatio	n, repetition period 313 x 10^9 years		
Carrier-to-noise ratio	± 100 dB when added to signal			
Carrier-to-noise ratio formats	C/N, Eb/No			
Carrier-to-noise ratio error	Magnitude error ≤ 0.2 dB at bas	eband I/Q outputs		
Custom modulation Arb Mode (Option	431)			
Modulation	PSK	BPSK, QPSK, OQPSK, π/4DQPSK, gray coded and unbalanced QPSK, 8PSK, 16PSK, D8PSK		
	QAM	4, 16, 32, 64, 128, 256, 1024 (and 89600 VSA mappings)		
	FSK	Selectable: 2,4,8, 16, C4FM		
	MSK	0 to 100 °		
	ASK	0 to 100%		
Multicarrier	Number of carriers	Up to 100 (limited by a max bandwidth of 160 MHz depending on symbol rate and modulation type)		
	Frequency offset (per carrier)	Up to -80 to +80 MHz		
	Power offset (per carrier)	0 dB to -40 dB		
Symbol rate	50 sps to 100 Msps			
Filter types	Nyquist, root-Nyquist, Gaussian	, rectangular, APCO 25 C4EM, user		
Quick setup modes	APCO 25w/C4FM, APCO25 w/CQPSK, <i>Bluetooth</i> ®, CDPD, DECT, EDGE, GSM, NADC, PDC, PHS, PWT, TETRA			
Data	Random only			

Custom modulation real-time m	DCIV	· .	BPSK, QPSK, OQPSK,		
Modulation	PSK	PSK			
	MAD	QAM			
		Selectable	2,4,8, 16 level symmetric, C4FM		
	FSK	User-defined	Custom map of up to 16 deviation levels		
		Max deviation	20 MHz		
	MSK	0 to 100 °			
	ASK	0 to 100%			
	Custom I/Q	Custom map of 1024 unique	e values		
Frequency offset	Up to -80 MHz to +80 MHz				
Symbol rate	Internal generated data	1 sps up to 100 Msps and ma	ax of 10 bits per symbol		
	External serial data	1 sps to [(50 Mbits/sec)/(#	tbits/symbol)]		
Filter types	Selectable	Nyquist, root-Nyquist, Gaussian, rectangular, APCO 25 (phase 1 and 2 UL and DL), IS-95, WCDMA,EDGE (wide a HSR)			
	Custom FIR	16-bit resolution, up to 64 syr resampled to 1024 coefficien > 32 to 64 symbol filter: symb > 16 to 32 symbol filter: symbol Internal filters switch to 16 to and 100 MHz	ents (max) mbol rate ≤ 12.5 MHz		
Quick setup modes		SK, HCPM, HDQPSK), TETRA , BI VT, WorldSpace, Iridium, ICO, CT			
Trigger delay	Range		0 to 1,048,575 bits		
	Resolution		1 bit		
Data types		Pseudo-random patterns	PN9, PN11, PN15, PN20, PN23		
	Internally generated	Repeating sequence	Any 4-bit sequence		
			32 Mb (standard)		
	Direct-pattern RAM [PRAM Note: Used for custom TDN		512 Mb (Option 022)		
	Note. Osed for custom 1D1	WA/ Holl-stalldard frailing	1024 Mb (Option 023)		
			32 MB (standard)		
	User file		512 MB (Option 022)		
			1024 MB (Option 023)		
	Externally streamed data	Туре	Serial data		
	(via AUX IO)	Inputs/outputs ¹	Data, symbol sync, bit clock		
Internal burst shape	Rise/fall time range	Rise/fall time range			
(varies with bit rate)	Rise /fall delay range	Rise/fall delay range			

^{1.} Bit clock and symbol sync inputs will be available in future firmware release.

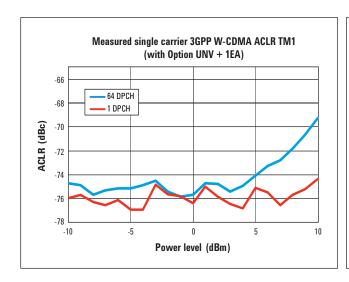
Multitone and two-tone (Option 430)			
Number of tones	2 to 64, with selectable on	off state per tone	
Frequency spacing	100 Hz to 160 MHz (Option	656 and 657)	
Phase (per tone)	Fixed or random		
Real-time phase noise impairments (Op	tion 432)		
Close-in phase noise characteristics	-20 dB per decade		
Far-out phase noise characteristics	-20 dB per decade		
Mid-frequency characteristics	Start frequency (f1)	Offset settable from 0 to 77 MHz	
	Stop frequency (f2)	Offset settable from 0 to 77 MHz	
Phase noise amplitude level (L(f))	User selected; max degrad	ation dependent on f2	

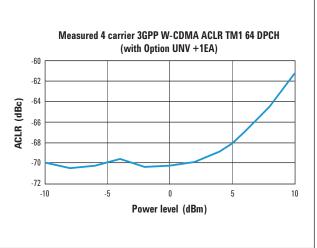


3GPP W-CDMA distortion performance 1,2								
			Standard		Option UI	NV	Option UI with Opti	
	Power level		≤ 2 dBm²	!	≤ 2 dBm	2	≤ 5 dBm	2
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур
Adjacent (5 MHz)	- 1 DPCH. 1 carrier	1800 to 2200 MHz	$-69\;\mathrm{dBc}$	-73 dBc	-71 dBc	-75 dBc	-71 dBc	-75 dBc
Alternate (10 MHz)	i Drun, i cainei	1000 to 2200 NID2	-70 dBc	-75 dBc	-72 dBc	-77 dBc	-71 dBc	-77 dBc
Adjacent (5 MHz)	Test model 1 with	1000 to 2200 MILI-	-68 dBc	-70 dBc	-71 dBc	-73 dBc	-71 dBc	-72 dBc
Alternate (10 MHz)	64 DPCH, 1 carrier	4 DPCH, 1 carrier 1800 to 2200 MHz		-73 dBc	-72 dBc	-76 dBc	-71 dBc	-76 dBc
Adjacent (5 MHz)	Test model 1 with 64 DPCH, 4 carrier 1800 to 2200 MHz	-63 dBc	-65 dBc	-65 dBc	-67 dBc	-64 dBc	-66 dBc	
Alternate (10 MHz)		-64 dBc	-66 dBc	-66 dBc	-68 dBc	-66 dBc	-68 dBc	

^{1.} ACPR specifications apply when the instrument is maintained within \pm 20 to 30 °C.

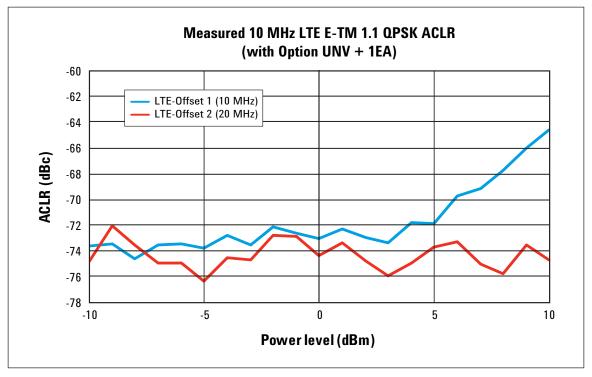
^{2.} This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5dB = +16.5 dBm PEP).





3GPP LTE-FDD distortion performance ¹								
			Standard		Option UI	٧V	Option UI with Opti	
	Power level		≤ 2 dBm	2	≤ 2 dBm	2	≤ 5 dBm	2
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур
Adjacent (10 MHz) ³	10 MHz E-TM 1.1	1800 to 2200 MHz	-64 dBc	-66 dBc	-67 dBc	-69 dBc	-64 dBc	-67 dBc
Alternate (20 MHz) ³	QPSK	1000 to 2200 NITZ		-68 dBc	-69 dBc	-71 dBc	-69 dBc	-71 dBc

- 1. ACPR specifications apply when the instrument is maintained within \pm 20 to 30 °C.
- 2. This is rms power. Convert from rms to peak envelope power with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5 dB = +16.5 dBm PEP).
- 3. ACPR measurement configuration: reference channel integration BW: 9.015 MHz, offset channel integration bandwidth: 9.015 MHz.



			GSM		EDGE	
Power level		< +7 dBm		< +7 dBm		
Offset	Configuration	Frequency 1	Standard, typical	Option UNV, typical	Standard, typical	Option UNV, typical
200 kHz			-34 dBc	-36 dBc	-37 dBc	–38 dBc
400 kHz			-69 dBc	-70 dBc	-69 dBc	-70 dBc
600 kHz	1 normal timeslot, - bursted	800 to 900 MHz 1800 to 1900 MHz	-81 dBc	-82 dBc	-80 dBc	-81 dBc
800 kHz	- nnieren 1000 f0 1800 fX	1000 to 1000 WILL	-82 dBc	-83 dBc	-82 dBc	-83 dBc
1200 kHz			-84 dBc	-85 dBc	-83 dBc	-84 dBc
3GPP2 cdma2000 d	listortion performand	ce, typical				
			Standard	Option UNV	Option UNV + 1E	:A
Powe	r level ²		≤ 2dBm	≤ 2 dBm	≤ 5 dBm	
Offset	Configuration	Frequency (1)	Typical	Typical	Typical	
885 kHz to 1.98 MHz			-78 dBc	-79 dBc	-77 dBc	
> 1.98 to 4.0 MHz	9 channel forward Iink	800 to 900 MHz	-86 dBc	-87 dBc	-87 dBc	
> 4.0 to 10 MHz	- IIIIK		-91dBc	-93 dBc	-93 dBc	
802.16e Mobile WiMA	X™ distortion perform	ance, measured				
Power	Offset ³	Configuration ⁴	Frequency	Standard, measured	UNV, measured	
<-7 dBm	10 MHz	QPSK	2.5 and 3.5 GHz	–65 dBc	-68 dBc	
Up to +5 dBm	10 MHz	QPSK	3.5 GHz	-62 dBc	-65 dBc	

^{1.} Performance evaluated at bottom, middle, and top of bands shown.

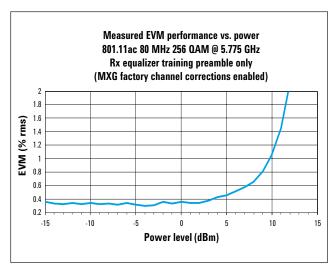
^{2.} This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example: 3GPP test model 1 with 64 DPCH has a crest factor > 11 dB, therefore at +5 dBm rms the PEP = 5 dBm + 11 dB = +16 dBm PEP).

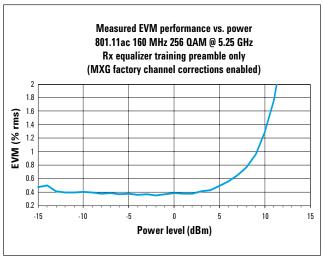
^{3.} Measurement configuration: reference channel integration BW: 9.5 MHz, offset channel integration BW: 9 MHz, channel offset: 10 MHz.

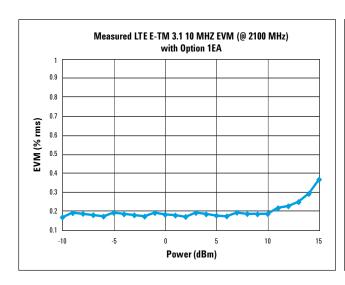
^{4. 802.16}e WiMAX signal configuration—bandwidth: 10 MHz, FFT: 1024, frame length: 5 ms, guard period: 1/8, symbol rolloff: 5%, content: 30 symbols of PN9 data.

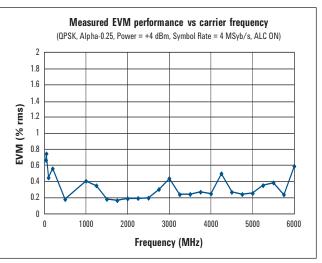
EVM performance	data 1, 2									
Format	GSM		EDGE		cdma2000/IS95A		W-CDMA		LTE FDD ³	
Modulation type	GMSK (burs	ted)	3pi/8 8PS	K (bursted)	ΩPSK		QPSK		64 QAM	
Modulation rate	270.833 ksp	S	70.833 ks	ps	1.2288 M	cps	3.84 Mcps		10 MHz BW	
Configuration	1 timeslot		1 timeslo	t	Pilot channel		1 DPCH		E-TM 3.1	
Frequency 4	800 to 900 N 1800 to 1900		800 to 900 MHz 1800 to 1900 MHz		800 to 900 MHz 1800 to 1900 MHz		1800 to 2	1800 to 2200 MHz		2200 MHz
EVM power level	≤ 7 dBm		≤ 7 dBm		≤ 7 dBm		≤ 7 dBm		≤ 7 dBm	
EVM power level with Option 1EA	≤ 13 dBm		≤ 13 dBm ≤ 13 dBm		1	≤ 13 dBm		≤ 13 dBm		
EVM/global phase error	Spec	Тур	Spec	Тур	Spec	Тур	Spec	Тур	Me	asured
	rms 0.8 °	0.2°	1.2%	0.75%	1.3%	0.8%	1.2%	0.8%	(0.2%
Format	802.11a/g	802.11ac 5	QPSK	QPSK			16 QAM			
Modulation type	64 QAM	256 QAM		QF	PSK		16 QAM			
Modulation rate	54 Mbps	80 MHz			4 Msp	s (root-Nyo	uist filter o	ı = 0.25)		
Frequency 4	2400 to 2484 MHz	5.775 GHz			≤ 6 GHz ≤ 3 GHz		≤ 6 GHz			
	5150 to 5825 MHz] ≤ 3	υπΖ	≥ 0	UHZ	> 3) UПZ		0 UHZ
EVM power level	≤ –5 dBm	≤ –5 dBm	≤ 4 dBm		≤ 4	dBm	≤ 4	dBm	≤ 4	1 dBm
EVM power level with Option 1EA	≤ 2 dBm	≤ 2 dBm	≤ 10 dBm		≤ 10) dBm	≤ 10	0 dBm	≤ 1	0 dBm
EVM	Measured	Measured	Spec	Тур	Spec	Тур	Spec	Тур	Spec	Тур
	0.3%	0.4%	1.2%	0.8%	1.9%	1.1%	1.1%	0.65%	1.5%	0.9%

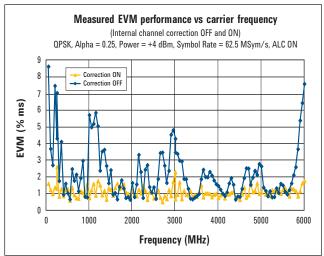
- 1. EVM specifications apply for the default ARB file setup conditions with the default ARB files supplied with the instrument.
- 2. EVM specifications apply after execution of I/O calibration when the instrument is maintained within \pm 5 °C of the calibration temperature.
- 3. LTE FDD E-TM 3.1,10 MHz, 64 QAM PDSCH, full resource block. Measured EVM after DC calibration.
- 4. Performance evaluated at bottom, middle, and top of bands shown.
- 5. WLAN 802.11ac 80 MHz, 256 QAM, MCS 8, 7 symbols, no filtering. Channel corrections enabled. Rx equalizer training preamble only.

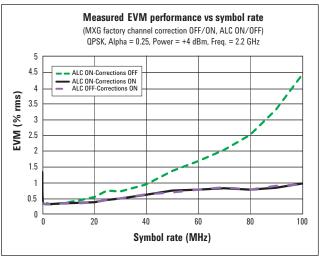












Bit error rate [BER] analyzer (Option UN7)	
Clock rate	100 Hz to 60 MHz (usable to 90 MHz)
Data patterns	PN9, 11, 15, 20, 23
Resolution	10 digits
Bit sequence length	100 bits to 4,294 Gbits after synchronization
Other features	Input clock phase adjustment and gate delay Direct measurement triggering Data and reference signal outputs Real-time display Bit count Error-bit-count
	Bit error rate Pass/fail indication Valid data and clock detection Automatic re-synchronization Special pattern ignore

General Specifications

Remote programming	
Interfaces	GPIB IEEE-488.2, 1987 with listen and talk
	LAN 1000BaseT LAN interface, LXI class C compliant
	USB Version 2.0
Control languages	Control languages SCPI Version 1997.0
Compatibility languages	Keysight Technologies: N5181A\61A, N 5182A\62A, N5183A, E4438C, E4428C, E442xB, E443xB, E8241A, E8244A, E8251A, E8254A, E8247C, E8257C/D, E8267C/D, 8648 Series, 8656B, E8663B, 8657A/B, 8662A, 8663A Aeroflex Incorporated: 3410 Series
	Rohde & Schwarz: SMB100A, SMBV100A, SMU200A, SMJ100A, SMATE200A, SMIQ, SML, SMV
Power requirements	
100-120 VAC, 50/60/400 Hz	
220-240 VAC, 50/60 Hz	
160 W maximum (N5181B)	
300 W maximum (N5182B)	
Operating temperature range	
0 to 55 °C	
Storage temperature range	
–40 to 70 °C	
Operating and storage altitude	
Up to 15,000 feet	
Humidity	
Relative humidity - type tested at 959	%, +40 °C (non-condensing)
Environmental stress	
Samples of this product have been ty	pe tested in accordance with the Keysight Environmental Test Manual and verified to be robust
	of storage, transportation and end-use; those stresses include but are not limited to temperature, nd power line conditions; test methods are aligned with IEC 60068-2 and levels are similar to MIL-
Safety	
Complies with European Low Voltage	P. Directive 2006/95/FC

- IEC/EN 61010-1, 2nd Edition - Canada: CSA C22.2 No. 61010-1	Acoustic noise emission LpA < 70 dB	Geraeuschemission LpA < 70 dB
- USA: UL std no. 61010-1, 2nd Edition	Operator position	Am Arbeitsplatz
German Acoustic statement	Normal position Per ISO 7779	Normaler Betrieb Nach DIN 45635 t.19

Complies with European EMC Directive 2004/108/EC

- IEC/EN 61326-1or IEC/EN 61326-2-1	This ISM device complies with Canadian ICES-001;
 CISPR Pub 11 Group 1, class A 	cet appareil ISM est conforme a la norme NMB-001 du Canada
AS/NZS CISPR 11	

Memory

- ICES/NMB-001

- Memory is shared by instrument states, user data files, sweep list files, waveform sequences, and other files
- $-\,$ 3 GB (30 GB with Option 009) memory available in the N5182B $-\,$ Security Option 006 allows storage of up to 8 GB on SD card
- Depending on how the memory is utilized, a maximum of 1000 instrument states can be saved

Security (Option 006)

- Removable 8 GB solid state memory (SD card) from rear panel
- User can force all files to be stored only on external memory card including instrument states, user data files, sweep list files, waveforms, waveform sequences, and other files.
- Memory sanitizing, memory sanitizing on, power on, and display blanking
 Note: Read/write speeds to external memory card will be slower compared to internal solid-state drive (Option 009)

Self-test

Internal diagnostic routines test most modules in a preset condition; for each module, if its node voltages are within acceptable limits, the module passes the test

Weight

N5181B: \leq 13.6 kg (30 lb) net, \leq 28.6 kg (63 lb.) shipping N5182B: \leq 15.9 kg (35 lb) net, \leq 30.8 kg (68 lb.) shipping

Dimensions

88 mm H x 426 mm W x 489 mm L (length includes rear panel feet)

(3.5 in H x 16.8 in W x 19.2 in L)

Max length (L) including RF connector tip to end of rear panel feet is 508 mm (20 in)

Recommended calibration cycle

36 months

ISO compliant

This instrument is manufactured in an ISO-9001 registered facility in concurrence with Keysight Technologies' commitment to quality.

Inputs and Outputs

Front panel connectors	
RF output	Outputs the RF signal via a precision N type female connector; see output section for reverse power protection information
I and Q inputs	BNC input accepts "in-phase" and "quadrature" input signals for I/Q modulation; nominal input impedance is 50 Ω , damage levels are 1 Vrms and 5 Vpeak
USB 2.0	Used with a memory stick for transferring instrument states, licenses and other files into or out of the instrument; also used with U2000, U848X and U202X Series USB power sensors.
Rear panel connectors	
Rear panel inputs and outputs are 3.3 V voltage levels	CMOS, unless indicated otherwise; CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL
RF output (Option 1EM)	Outputs the RF signal via a precision N type female connector
I and Q inputs (Option 1EM)	Accepts "in-phase" and "quadrature" input signals for I/Q modulation SMB connector, nominal input impedance is 50 Ω ; damage levels are 1 Vrms and 5 Vpeak; Option 1EM units will come with 2 SMB to BNC adapters
I and Ω outputs	BNC outputs the analog I/Q modulation signals from the internal baseband generator; nominal output impedance 50 Ω , DC coupled; damage levels \pm 2 V
I bar and Q bar outputs (Option 1EL)	BNC outputs the complement of the I and Q signals for differential applications;
Event 1	This connector outputs the programmable timing signal generated by marker 1 The marker signal can also be routed internally to control the RF blanking and ALC hold functions; this signal is also available on the AUX I/O connector With bit error rate analyzer (Option UN7) this connector is used for data input Damage levels are > +8 V and < -4 V
Pattern trigger	Accepts signal to trigger internal pattern generator to start single pattern output, for use with the internal baseband generators Accepts CMOS signal with minimum pulse width of 10 ns Female BNC Damage levels are > +8 V and < -4 V
BBTRIG 1	For arbitrary and real-time baseband generators I/O such as Markers or trigger inputs With bit error rate analyzer (Option UN7) this connector is used for clock input
BBTRIG 2	For arbitrary and real-time baseband generators I/O such as Markers or trigger inputs With bit error rate analyzer (Option UN7) this connector is used for gate input
Sweep out	Generates output voltage, 0 to +10 V when the signal generator is sweeping; this output can also be programmed to indicate when the source is settled or output pulse video and is TTL and CMOS compatible in this mode; output impedance < 1 Ω , can drive 2 k Ω ; damage levels are \pm 15 V
Ext 1	External AM/FM/PM #1 input; nominal input impedance is 50 $\Omega/600~\Omega/1M~\Omega,$ nominal; damage levels are \pm 5 V
Ext 2	External AM/FM/PM #2 input; nominal input impedance is 50 $\Omega/600~\Omega$ /1M $\Omega,$ nominal; damage levels are \pm 5 V
LF OUT	0 to 5 V peak into 50 Ω, –5 V to 5 V offset, nominal
Pulse	External pulse modulation input; this input is TTL and CMOS compatible; low logic levels are 0 V and high logic levels are ± 1 V; nominal input impedance is 50 ± 1 ; input damage levels are ± 1 0.3 V and ± 1 1.3 V

Trigger in	Accepts TTL and CMOS level signals for triggering point-to-point in sweep mode; damage levels are \leq -0.3 V and \geq +5.3 V
Trigger out	Outputs a TTL and CMOS compatible level signal for use with sweep mode The signal is high at start of dwell, or when waiting for point trigger in manual sweep mode, and low when dwell is over or point trigger is received This output can also be programmed to indicate when the source is settled, pulse synchronization, or pulse video Nominal output impedance $50~\Omega$ Input damage levels are $\leq -0.3~V$ and $\geq +5.3~V$
Reference input	Accepts a 10 MHz reference signal used to frequency lock the internal timebase; Option 1ER adds the capability to lock to a frequency from 1 MHz to 50 MHz; nominal input level -3 to $+20$ dBm, impedance $50~\Omega$, sine or square waveform
10 MHz out	Outputs the 10 MHz reference signal used by internal timebase; level nominally $+3.9$ dBm; nominal output impedance 50 Ω ; input damage level is $+16$ dBm
LO in (Option 012)	Accepts a signal from a master signal generator that is used as the LO for MXG vector in order to configure a phase coherent system; nominal input levels between 0 to +12 dBm; nominal input impedance 50 Ω
LO out (Option 012)	Outputs a reference signal that can be used in a phase coherent system; nominal output levels between 0 to +12 dBm; nominal output impedance 50 Ω
DAC Clk In (Option 012)	Reserved for future use.
Digital bus I/O	To be used with PXB or N5102A digital signal interface module
Aux IO	Aux IO port sends and/or receives auxiliary signaling information: For Option UN7 this connector is used to output reference data, clock, error signals, and more Output markers to an external device from arbitrary waveform or real-time generation application such as: frame markers, pulse-per-second, even-second, and more. Input signals from external DUT to modify characteristics of a signal being generated such as changing output power (power control loop testing), advancing or delaying timing (timing advance loop testing), HARQ ACK/NAK delivery (HARQ process loop testing) or streaming external data, clock and symbol synch for custom modulation. IO is application specific (CDMA, 3GPP, GNSS, LTE, custom). See User Guide or Signal Studio help for more details. Connector type: 36 pin 3M connector (part number N10236-52B2PC). The mating connector is a 3M 10136-3000 wire mount plug or 3M 10136-8000 IDC plug with a 3M 10336 shell. For Option 431 real-time custom modulation the follow pin numbers are assigned: Data input = pin 23 Data clock input = pin 29 Symbol sync input = pin 25 Burst input = pin 35 Data clock output = pin 35 Data clock output = pin 37 Event 1 output = pin 1 Event 2 output = pin 33
USB 2.0	The USB connector provides remote programming functions via SCPI
LAN (1000 BaseT)	The LAN connector provides the same SCPI remote programming functionality as the GPIB connector and is also used to access the internal Web server and FTP server Supports DHCP, sockets SCPI, VXI-11 SCPI, connection monitoring, dynamic hostname services,
	TCP keep alive LXI class C compliant Trigger response time for the immediate LAN trigger is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical; delayed/alarm triger is unknown Trigger output response time is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical

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Related Literature

Keysight X-Series Signal Generators

MXG Configuration Guide 5990-9959EN

EXG Data Sheet 5991-0039EN

EXG Configuration Guide 5990-9958EN

X-Series Signal Generator Brochure 5990-9957EN

Signal Studio Software Brochure 5989-6448EN

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